

GaN Amplifier, 50 V, 450 W 2.75 - 3.75 GHz



MACOM PURE CARBIDE™

CGHV38375F
Rev. V2

Features

- Full S-Band Radar Coverage
- Saturated Power: 450 W
- Large Signal Gain: >10 dB
- Drain Efficiency: 55%
- Internally Matched: 50 Ω
- Pulsed and CW Operation

Applications

- Civil & Military, Pulsed and CW S-Band Radar

Description

The CGHV38375F is a packaged, 450 W HPA matched to 50 ohms at both input and output ports. The CGHV38375F operates from 2.75 - 3.75 GHz providing coverage over the entire S-Band radar band. This high-power amplifier provides >10 dB of large signal gain and 40% power-added efficiency and is ideally suited as a high-power building block supporting both pulsed and CW radar applications.

Typical RF Performance:

Measured at fixed input power of +46 dBm, 100 μ s pulse width, 10% duty cycle.

- $V_{DS} = 50$ V, $I_{DQ} = 500$ mA, $T_C = 25^\circ\text{C}$

Frequency (GHz)	Output Power (dBm)	Gain (dB)	η_D (%)
2.75	55.9	9.9	50
2.9	57.4	11.4	67
3.3	57.5	11.5	62
3.5	57.7	11.7	60
3.75	56.8	10.8	60

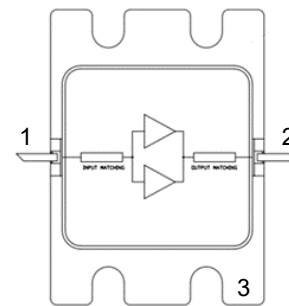
Ordering Information

Part Number	Package
CGHV38375F	Bulk
CGHV38375F-AMP	Sample Board



440226

Functional Schematic



Pin Configuration

Pin #	Description
1	Gate / RF Input
2	Drain / RF Output
3	Source / Flange

* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

1

MACOM Technology Solutions Inc. (MACOM) and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. Visit www.macom.com for additional data sheets and product information.

For further information and support please visit:
<https://www.macom.com/support>

DC-0030681

RF Electrical Specifications: Freq. = 2.75 - 3.75 GHz, T_A = +25C, V_{DD} = 50 V, I_{DQ} = 500 mA

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Output Power	P _{IN} = 46 dBm, Pulse Width = 100 μs, Duty Cycle = 10% 2.75 GHz 2.9 GHz 3.3 GHz 3.5 GHz 3.75 GHz	dBm	54.0 56.5 56.5 56.0 55.75	55.8 57.5 57.8 57.5 56.9	—
Drain Efficiency	P _{IN} = 46 dBm, Pulse Width = 100 μs, Duty Cycle = 10% 2.75 GHz 2.9 GHz 3.3 GHz 3.5 GHz 3.75 GHz	%	31.0 53.5 52.0 47.0 52.0	42.8 60.5 63.2 58.6 61.9	—
Small Signal Gain	P _{IN} = -10 dBm 2.75 GHz 2.9 GHz 3.3 GHz 3.5 GHz 3.75 GHz	dB	6.5 10.0 9.0 9.0 9.5	9.4 12.9 13.5 13.3 13.1	—
Input Return Loss	P _{IN} = -10 dBm	dB	—	6	—
Output Return Loss	P _{IN} = -10 dBm	dB	—	6	—
Output Mismatch Stress (VSWR)	No damage at all phase angles	Ψ	—	5:1	—

Note: Final testing and screening for all amplifier sales is performed using the CGHV38375F-AMP at 2.75-3.75 GHz.

DC Electrical Specifications: Freq. = 2.75 - 3.75 GHz, T_A = +25C

Parameter	Test Conditions	Units	Min.	Typ.	Max.
Gate Threshold Voltage	V _{DS} = 10 V, I _D = 83.6 mA	V	-3.8	-3.0	-2.3
Gate Quiescent Voltage	V _{DD} = 28 V, I _{DQ} = 500 mA	VDC	—	-2.7	—
Saturated Drain Current	V _{DS} = 6.0 V, V _{GS} = 2.0 V	A	54.4	77.7	—
Drain Source Breakdown Voltage	V _{GS} = -8 V, I _D = 83.6 mA	V	125	—	—

Absolute Maximum Ratings^{1,2}

Parameter	Absolute Maximum
Drain-Source Voltage	150 V
Gate Voltage	-10, +2 V
DC Drain Current	14 A
Gate Current	102 mA
Input Power	48 dBm
Storage Temperature	-55°C to +150°C
Mounting Temperature	+320°C
Junction Temperature ^{3,4,5}	+225°C
Operating Temperature	-40°C to +85°C

1. Exceeding any one or combination of these limits may cause permanent damage to this device.
2. MACOM does not recommend sustained operation near these survivability limits.
3. Operating at nominal conditions with $T_J \leq +225^\circ\text{C}$ will ensure $\text{MTTF} > 1 \times 10^6$ hours.
4. Junction Temperature (T_J) = $T_C + \theta_{jc} * (V * I)$
Typical thermal resistance (θ_{jc}) = 0.22 °C/W for 100 μs /10%.
 - a) For $T_C = +25^\circ\text{C}$,
 $T_J = 121^\circ\text{C}$ @ $P_{\text{DISS}} = 437 \text{ W}$
 - b) For $T_C = +85^\circ\text{C}$,
 $T_J = 179^\circ\text{C}$ @ $P_{\text{DISS}} = 427 \text{ W}$
5. Junction Temperature (T_J) = $T_C + \theta_{jc} * (V * I)$
Typical thermal resistance (θ_{jc}) = 0.5 °C/W for CW.
 - a) For $T_C = +85^\circ\text{C}$,
 $T_J = 185^\circ\text{C}$ @ $P_{\text{DISS}} = 200 \text{ W}$

Handling Procedures

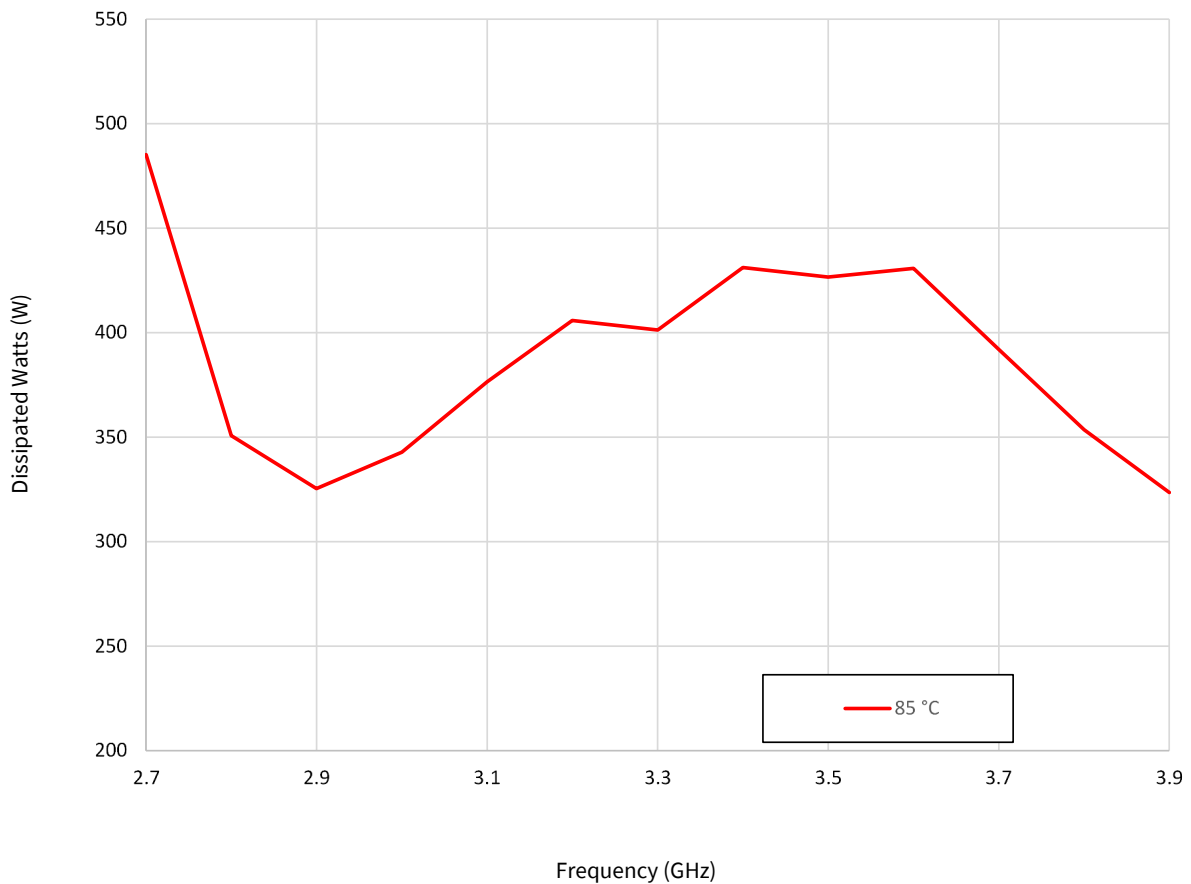
Please observe the following precautions to avoid damage:

Static Sensitivity

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Thermal Characteristics

Parameter	Operating Conditions	Value
Operating Junction Temperature (T_J)	Freq = 3.5 GHz, $V_D = 50$ V, $I_{DQ} = 500$ mA, $I_{DRIVE} = 18.59$ A, $P_{IN} = 46$ dBm, $P_{OUT} = 57.3$ dBm, $P_{DISS} = 426.5$ W, $T_C = 85^\circ\text{C}$, PW = 100 μs , DC = 10%	179°C
Thermal Resistance, Junction to Case ($R_{\theta JC}$)		0.22°C/W

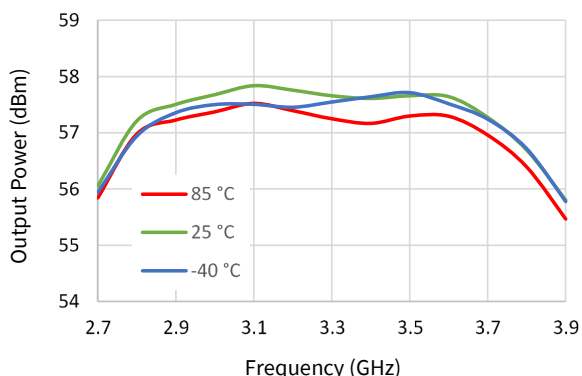


For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

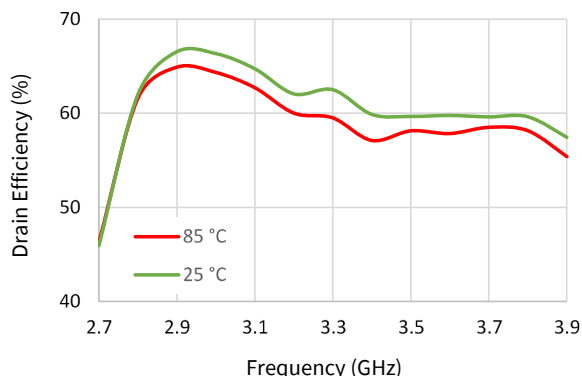
Typical Performance Curves:

$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, Pulse Width = 100 μs , Duty Cycle = 10%, $P_{IN} = 46\text{ dBm}$, $T_B = +25^\circ\text{C}$.
For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

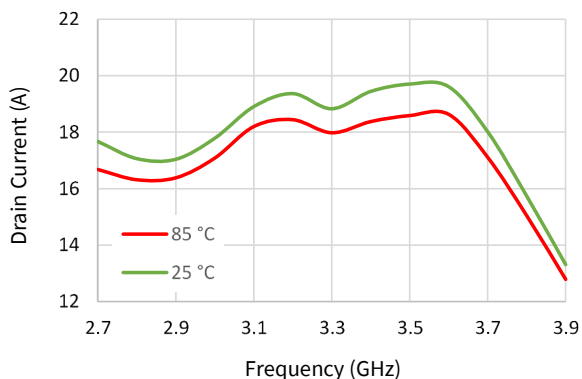
Output Power vs. Frequency vs. Temperature



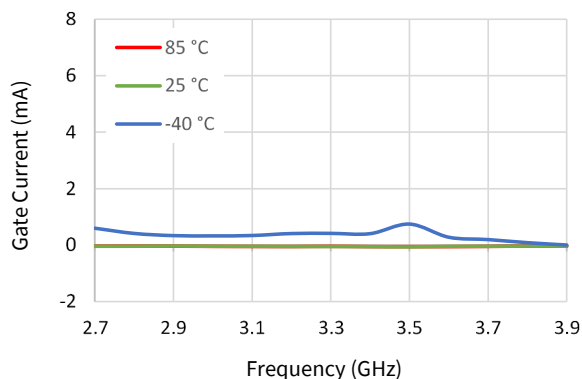
Drain Efficiency vs. Frequency vs. Temperature



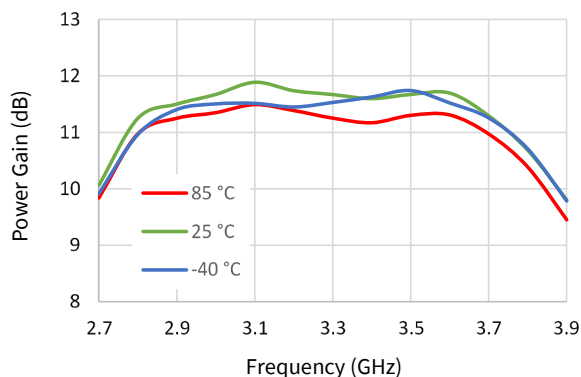
Drain Current vs. Frequency vs. Temperature



Gate Current vs. Frequency vs. Temperature



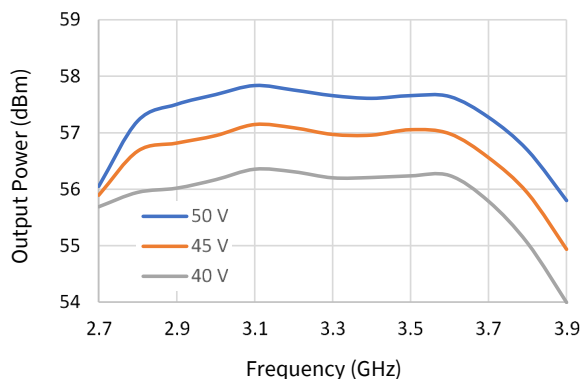
Power Gain vs. Frequency vs. Temperature



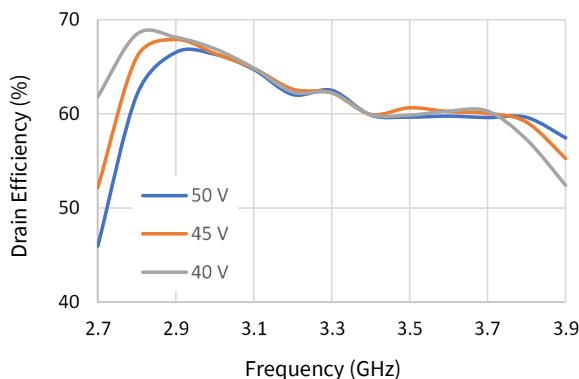
Typical Performance Curves:

$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, Pulse Width = 100 μs , Duty Cycle = 10%, $P_{IN} = 46\text{ dBm}$, $T_B = +25^\circ\text{C}$.
For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

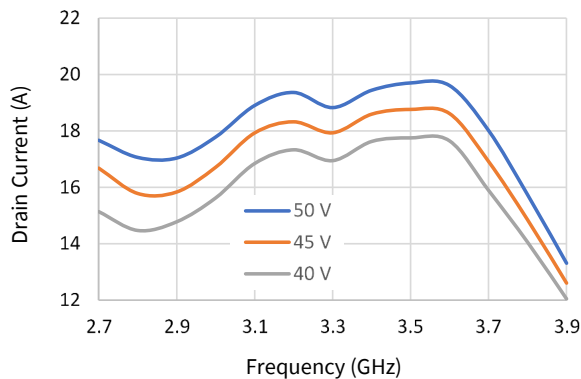
Output Power vs. Frequency vs. V_{DS}



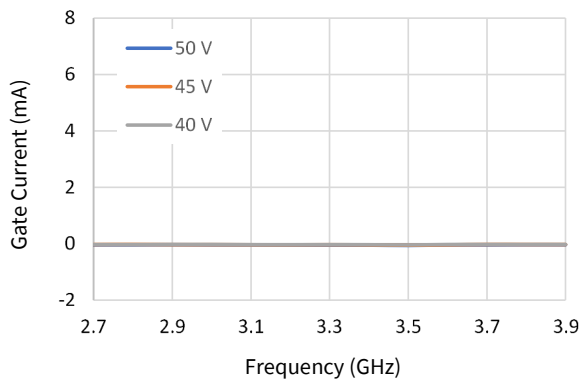
Drain Efficiency vs. Frequency vs. V_{DS}



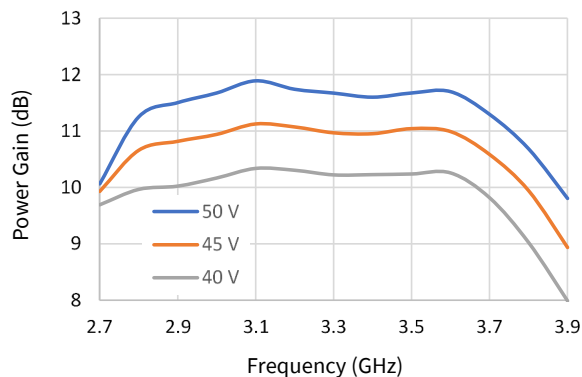
Drain Current vs. Frequency vs. V_{DS}



Gate Current vs. Frequency vs. V_{DS}



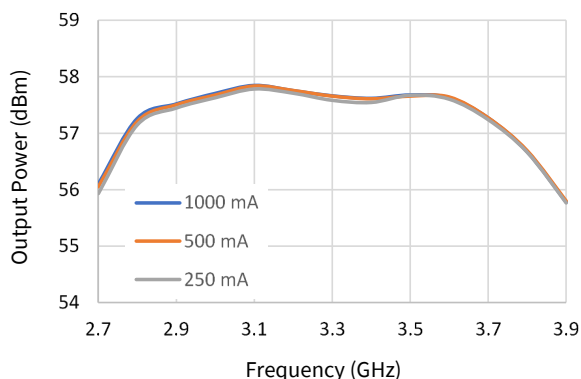
Power Gain vs. Frequency vs. V_{DS}



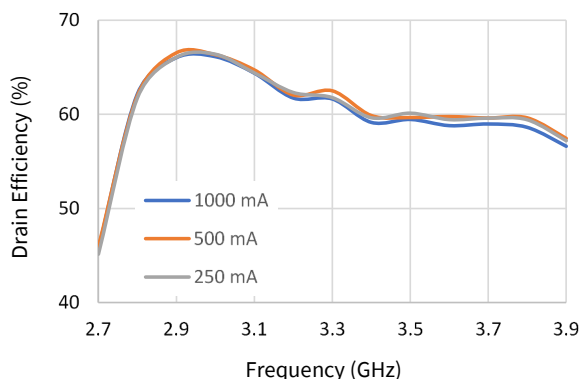
Typical Performance Curves:

$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, Pulse Width = 100 μs , Duty Cycle = 10%, $P_{IN} = 46\text{ dBm}$, $T_B = +25^\circ\text{C}$.
For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

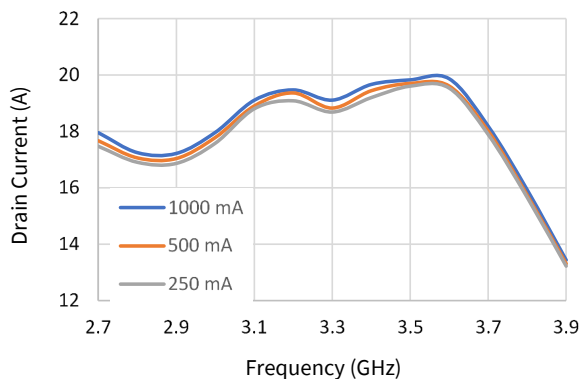
Output Power vs. Frequency vs. I_{DQ}



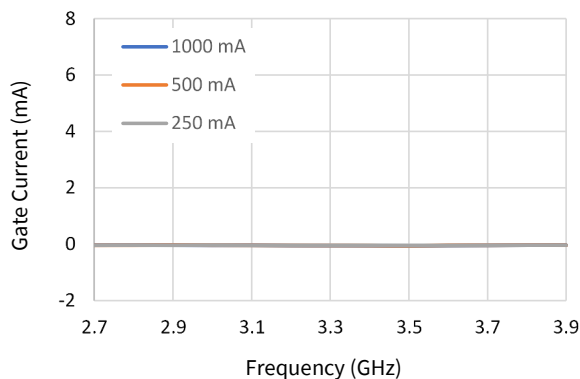
Drain Efficiency vs. Frequency vs. I_{DQ}



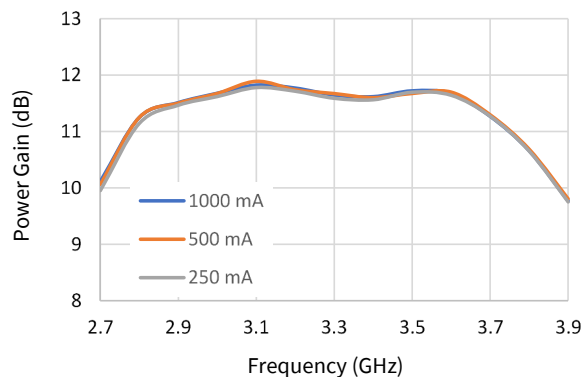
Drain Current vs. Frequency vs. I_{DQ}



Gate Current vs. Frequency vs. I_{DQ}



Power Gain vs. Frequency vs. I_{DQ}

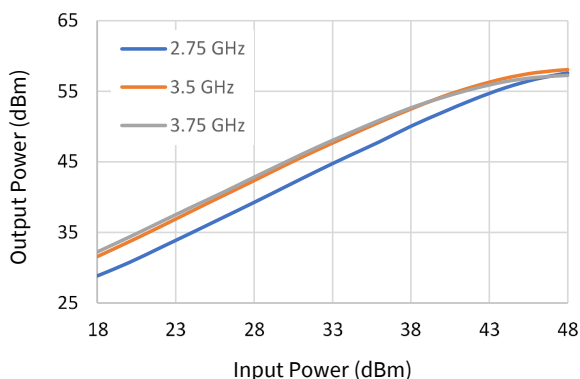


Typical Performance Curves:

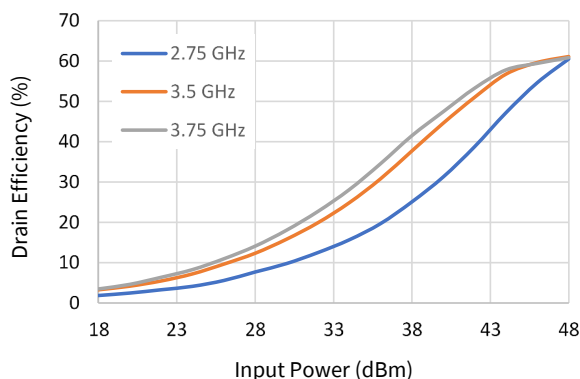
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, Pulse Width = 100 μs , Duty Cycle = 10%, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

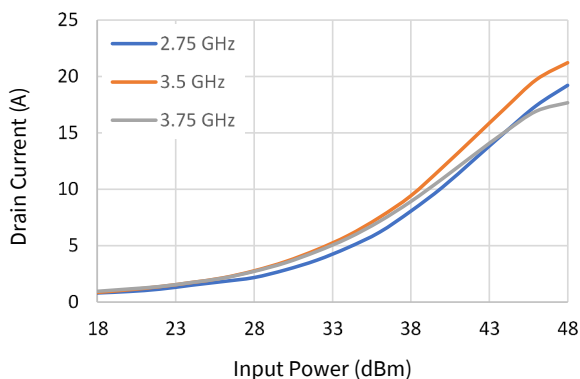
Output Power vs. Input Power vs. Frequency



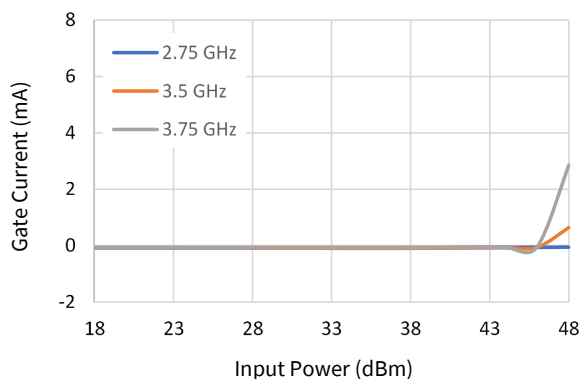
Drain Efficiency vs. Input Power vs. Frequency



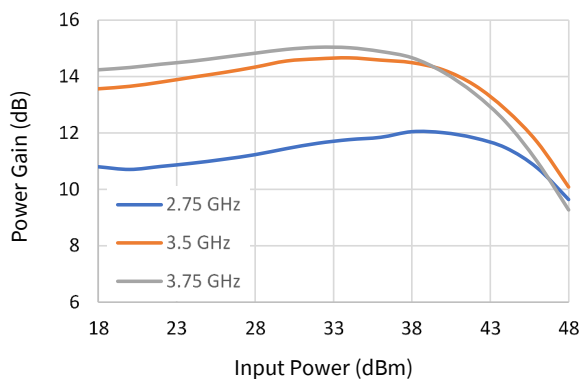
Drain Current vs. Input Power vs. Frequency



Gate Current vs. Input Power vs. Frequency



Power Gain vs Input Power vs. Frequency

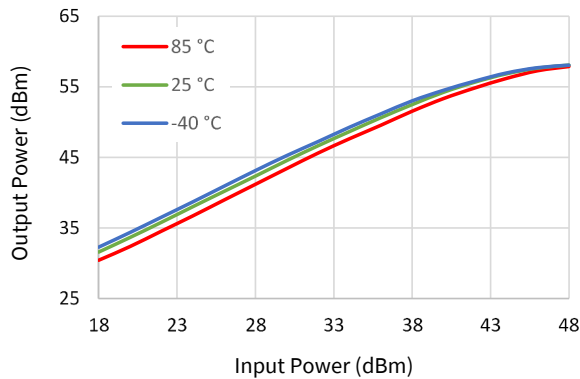


Typical Performance Curves:

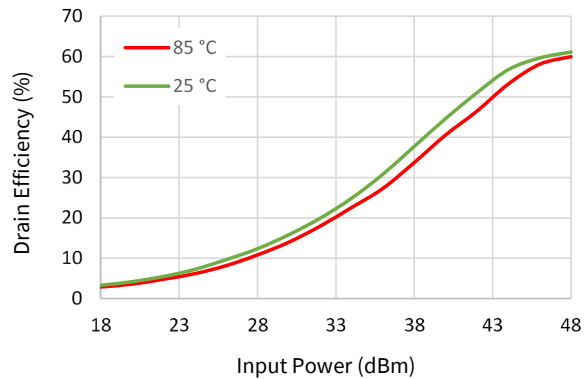
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, Pulse Width = 100 μs , Duty Cycle = 10%, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

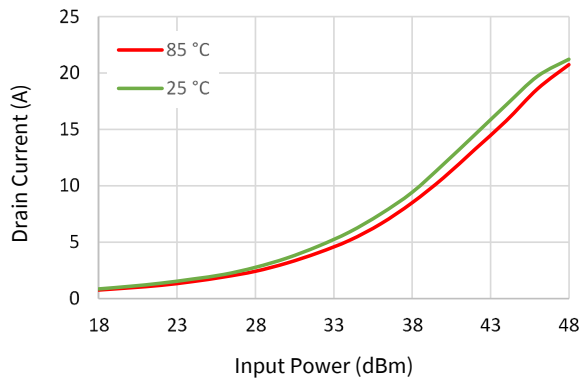
Output Power vs. Input Power vs. Temperature



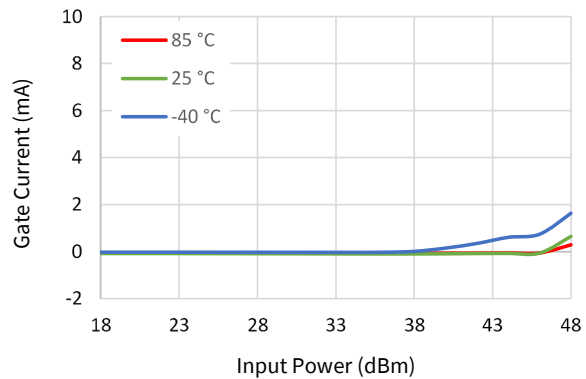
Drain Efficiency vs. Input Power vs. Temperature



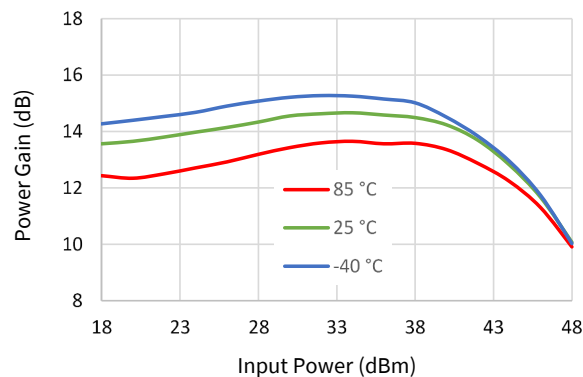
Drain Current vs. Input Power vs. Temperature



Gate Current vs. Input Power vs. Temperature



Power Gain vs. Input Power vs. Temperature

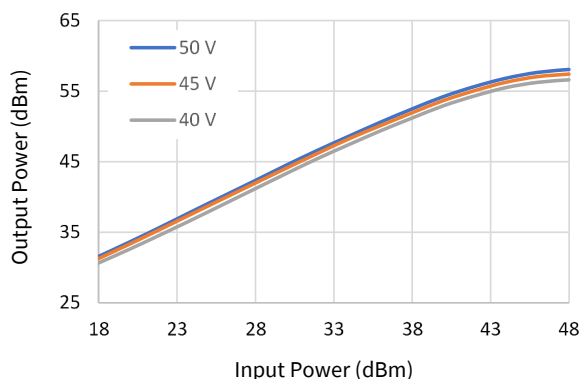


Typical Performance Curves:

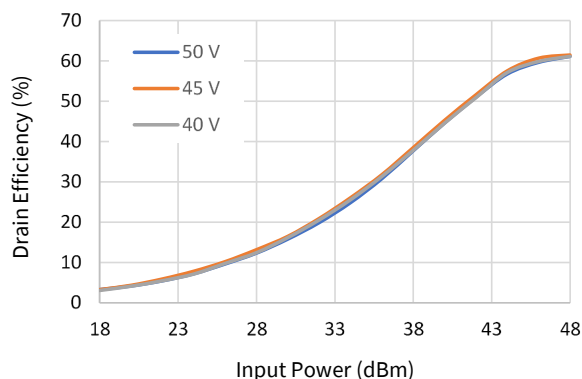
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, Pulse Width = 100 μs , Duty Cycle = 10%, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

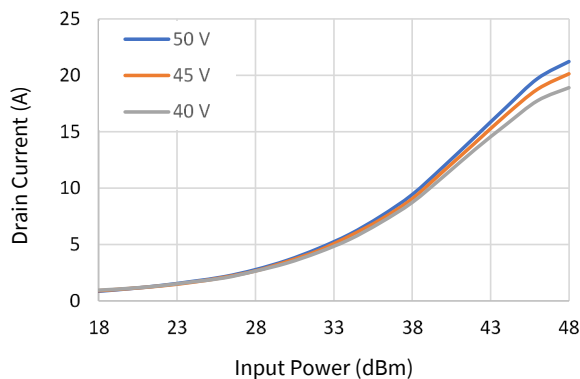
Output Power vs. Input Power vs. V_{DS}



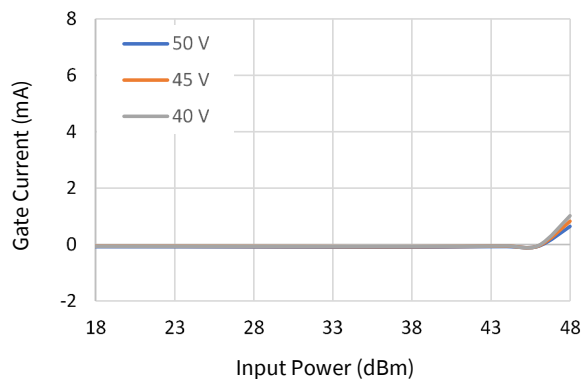
Drain Efficiency vs. Input Power vs. V_{DS}



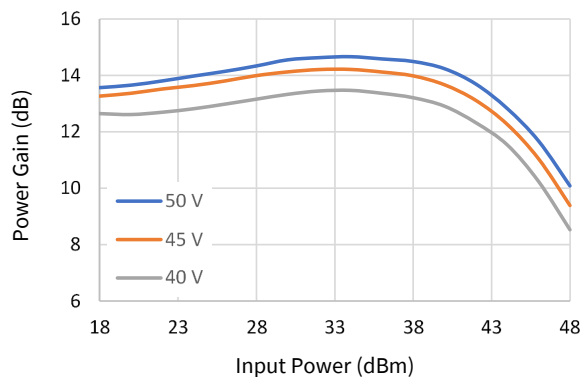
Drain Current vs. Input Power vs. V_{DS}



Gate Current vs. Input Power vs. V_{DS}



Power Gain vs. Input Power vs. V_{DS}

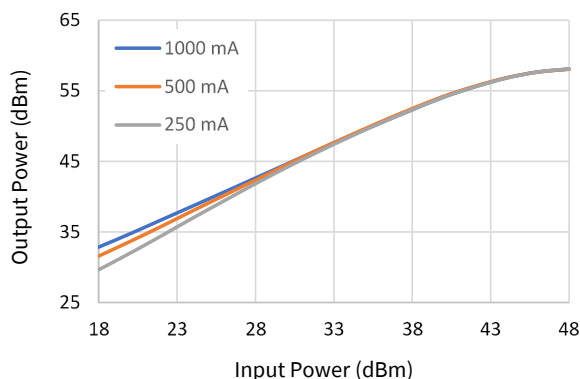


Typical Performance Curves:

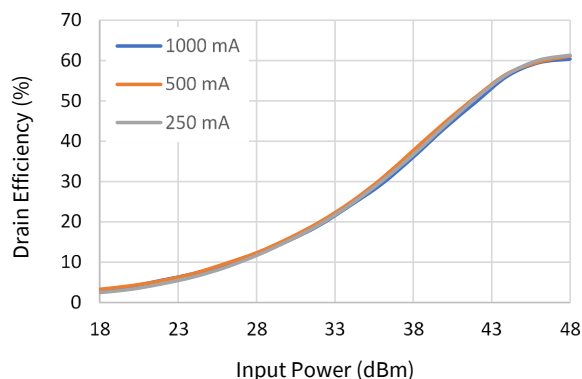
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, Pulse Width = 100 μs , Duty Cycle = 10%, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

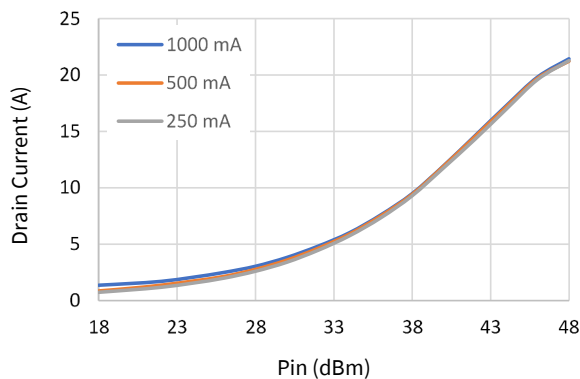
Output Power vs. Input Power vs. I_{DQ}



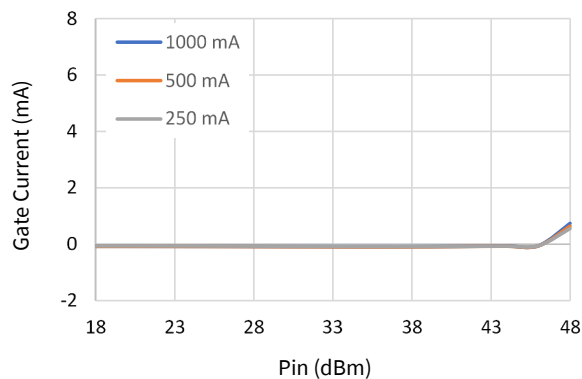
Drain Efficiency vs. Input Power vs. I_{DQ}



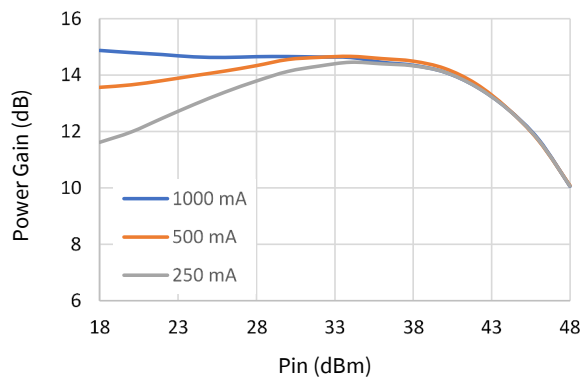
Drain Current vs. Input Power vs. I_{DQ}



Gate Current vs. Input Power vs. I_{DQ}



Power Gain vs. Input Power vs. I_{DQ}

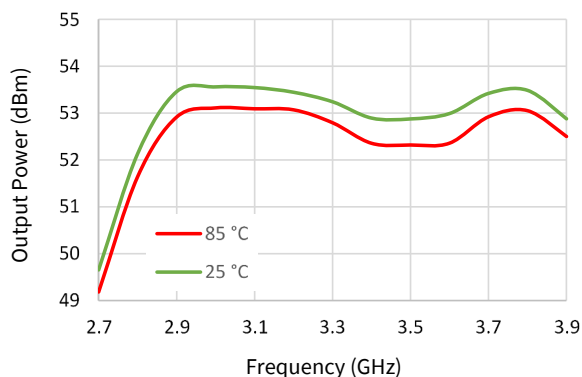


Typical Performance Curves:

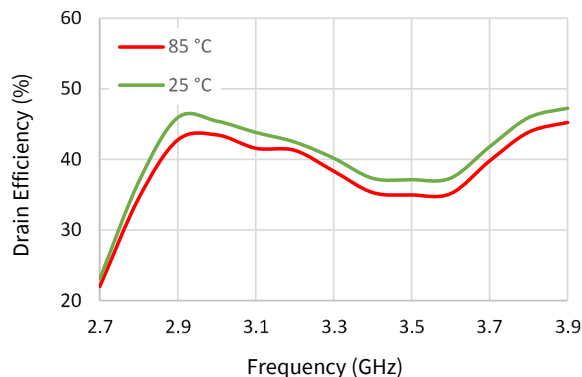
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, CW, $P_{IN} = 43\text{ dBm}$, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

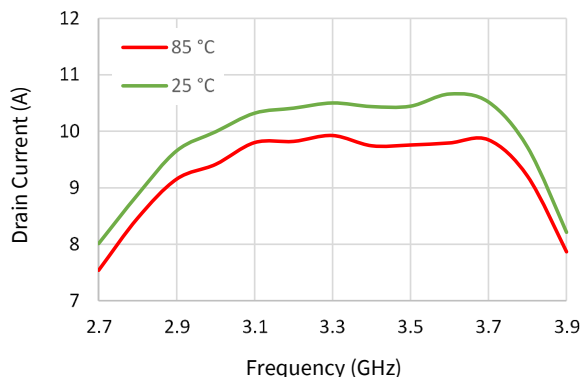
Output Power vs. Frequency vs. Temperature



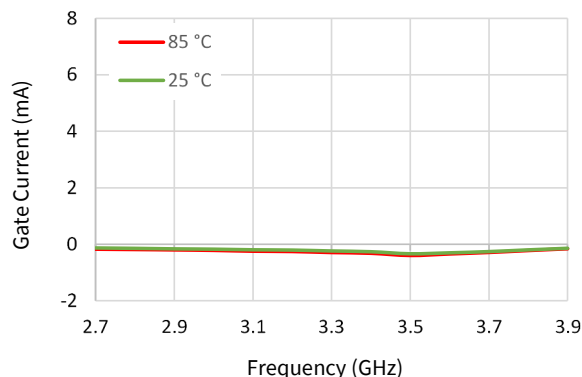
Drain Efficiency vs. Frequency vs. Temperature



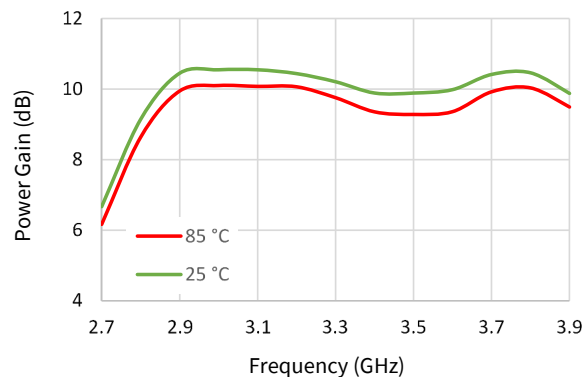
Drain Current vs. Frequency vs. Temperature



Gate Current vs. Frequency vs. Temperature



Power Gain vs. Frequency vs. Temperature

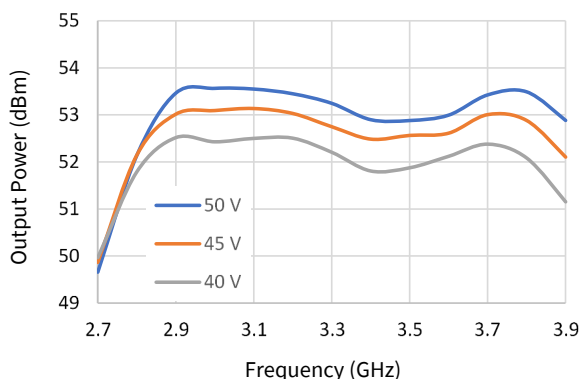


Typical Performance Curves:

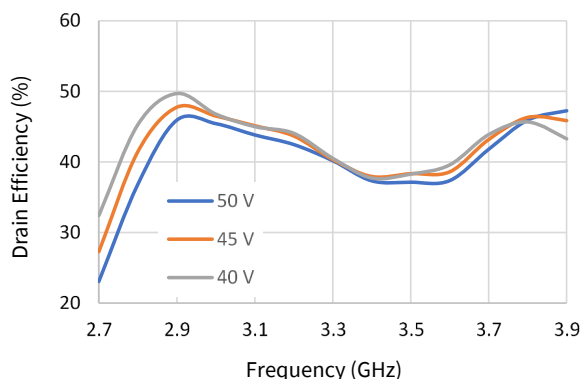
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, CW, $P_{IN} = 43\text{ dBm}$, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

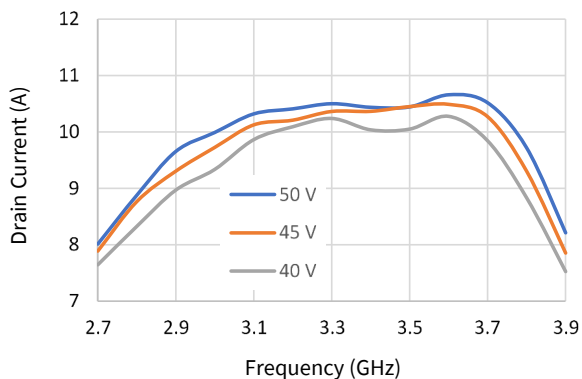
Output Power vs. Frequency vs. V_{DS}



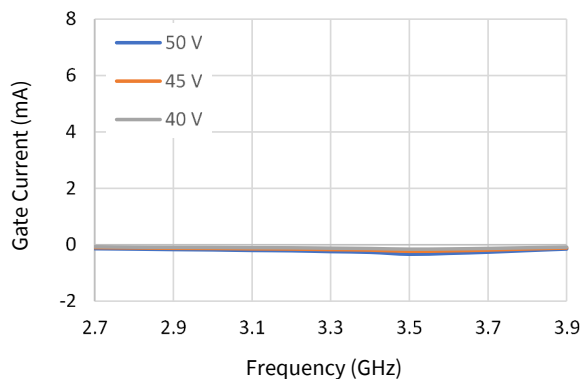
Drain Efficiency vs. Frequency vs. V_{DS}



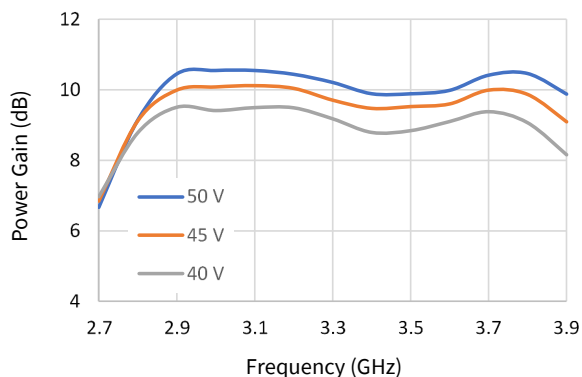
Drain Current vs. Frequency vs. V_{DS}



Gate Current vs. Frequency vs. V_{DS}



Power Gain vs. Frequency vs. V_{DS}

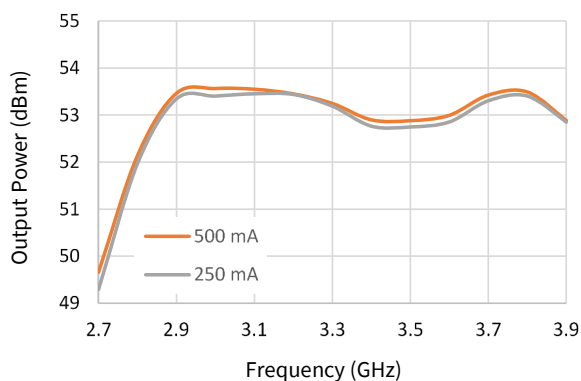


Typical Performance Curves:

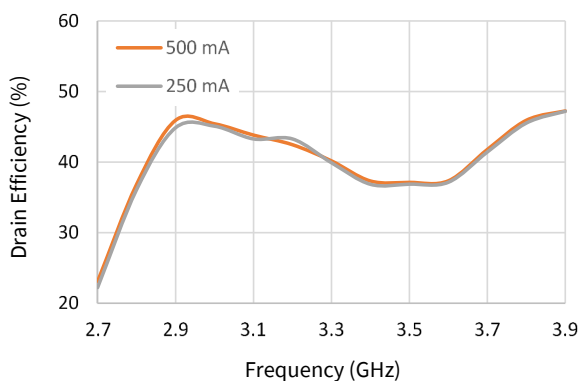
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, CW, $P_{IN} = 43\text{ dBm}$, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM’s Datasheet Limits.

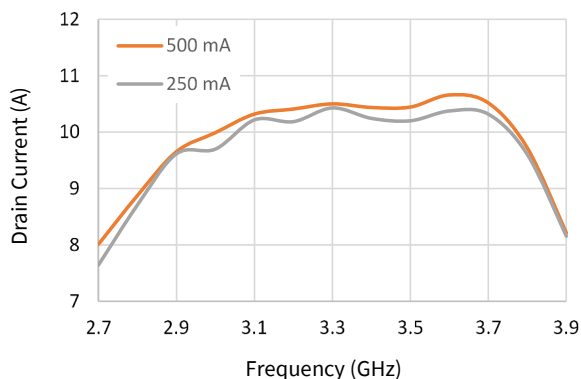
Output Power vs. Frequency vs. I_{DQ}



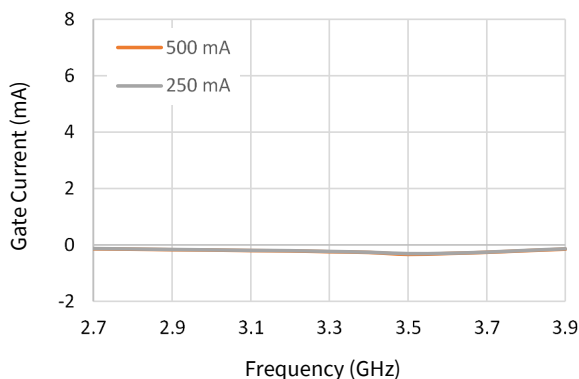
Drain Efficiency vs. Frequency vs. I_{DQ}



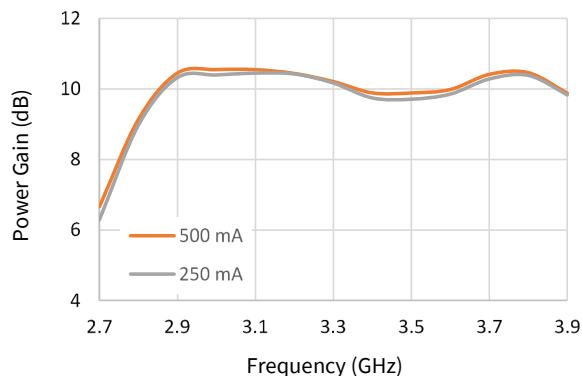
Drain Current vs. Frequency vs. I_{DQ}



Gate Current vs. Frequency vs. I_{DQ}



Power Gain vs. Frequency vs. I_{DQ}

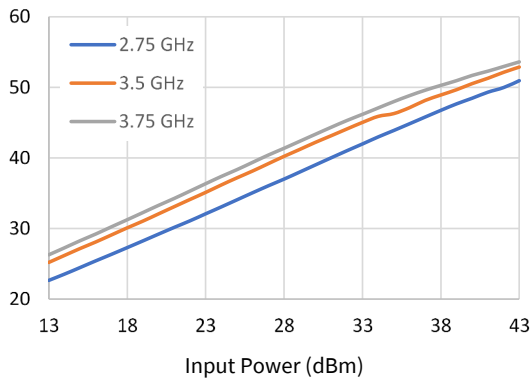


Typical Performance Curves:

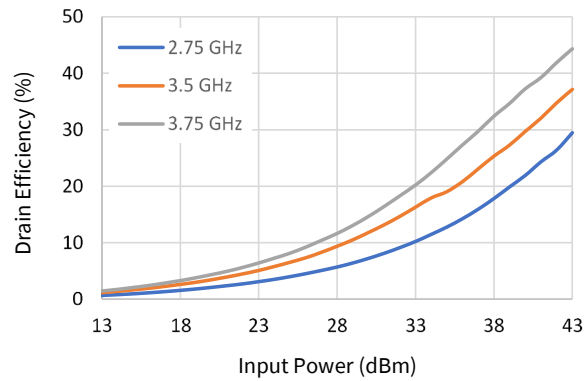
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, CW, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

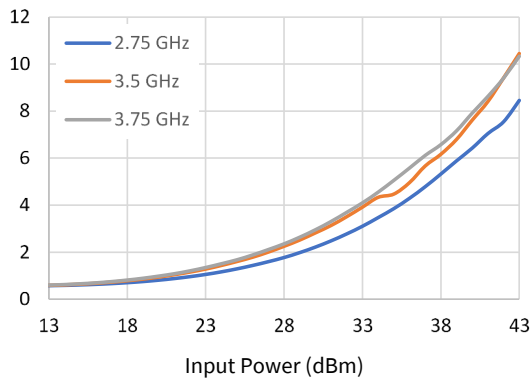
Output Power vs. Input Power vs. Frequency



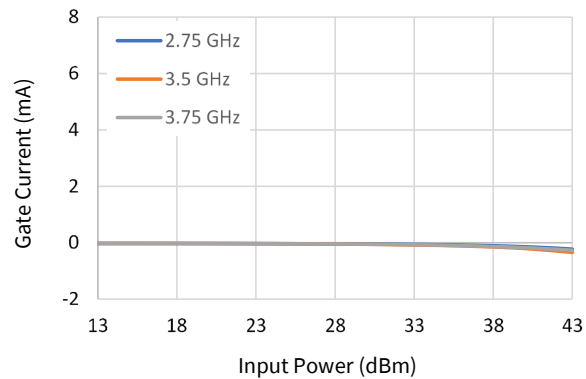
Drain Efficiency vs. Input Power vs. Frequency



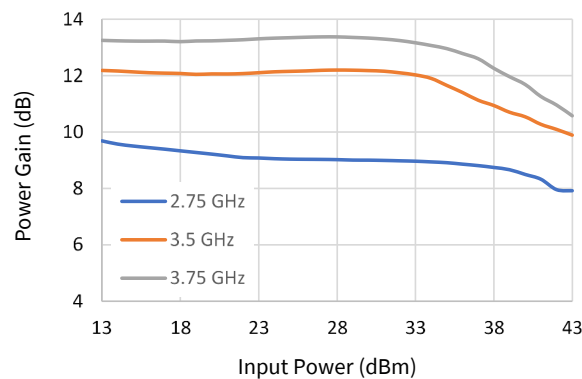
Drain Current vs. Input Power vs. Frequency



Gate Current vs. Input Power vs. Frequency



Power Gain vs. Input Power vs. Frequency

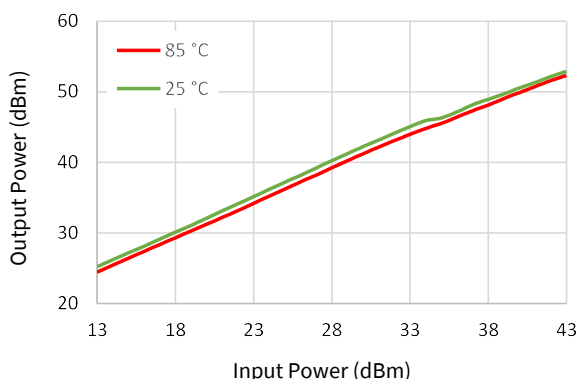


Typical Performance Curves:

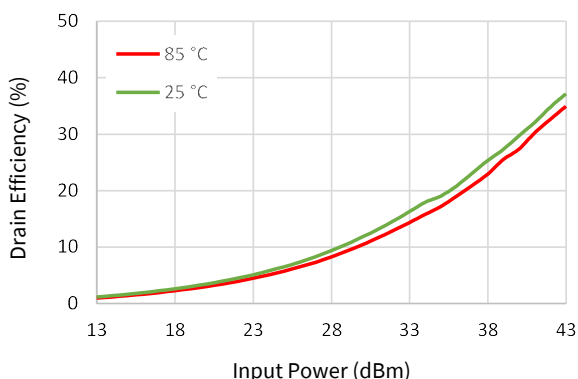
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, CW, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

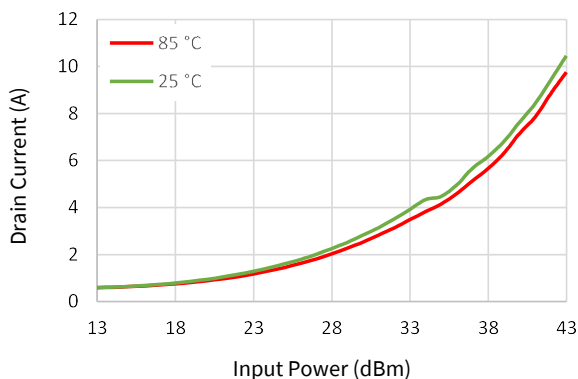
Output Power vs. Input Power vs. Temperature



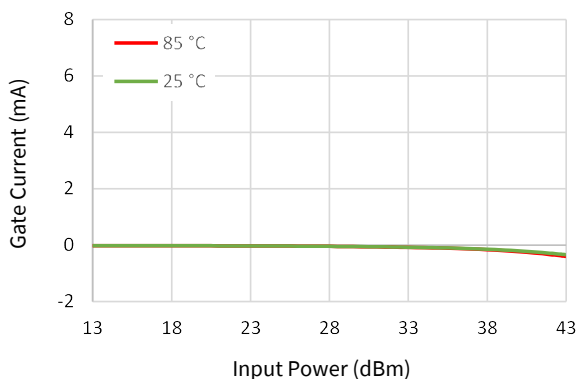
Drain Efficiency vs. Input Power vs. Temperature



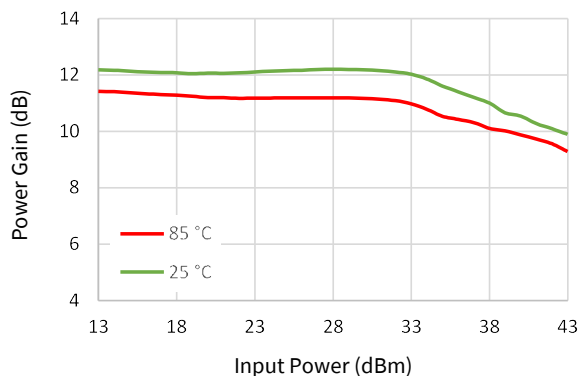
Drain Current vs. Input Power vs. Temperature



Gate Current vs. Input Power vs. Temperature



Power Gain vs. Input Power vs. Temperature

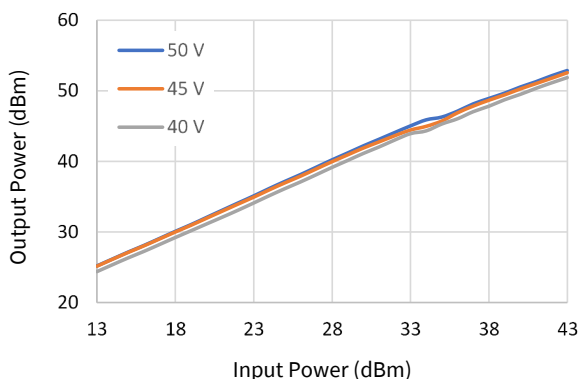


Typical Performance Curves:

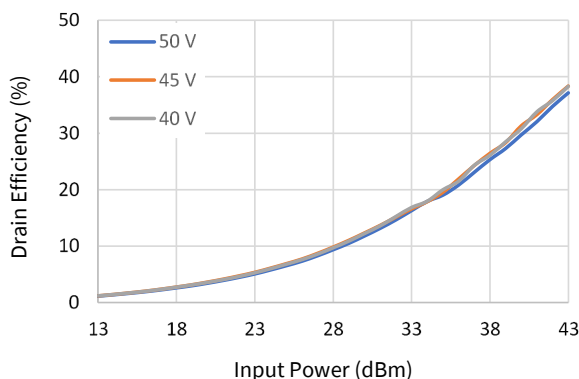
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, CW, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

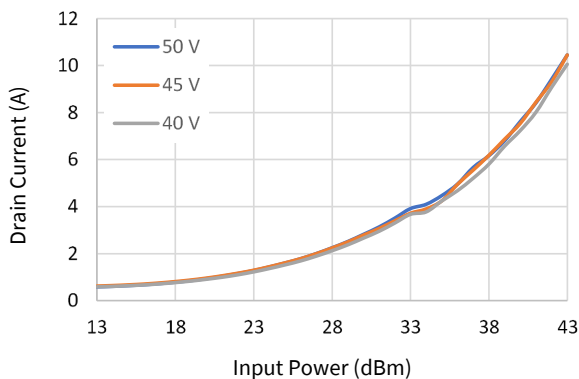
Output Power vs. Input Power vs. V_{DS}



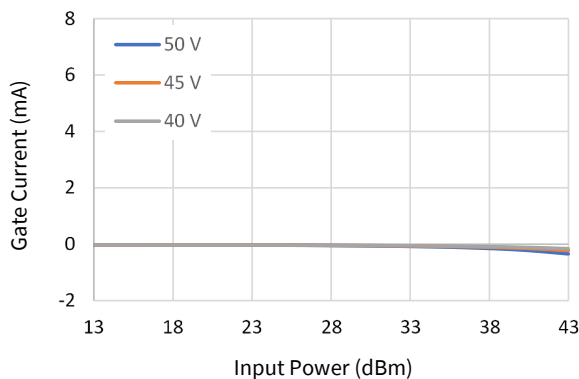
Drain Efficiency vs. Input Power vs. V_{DS}



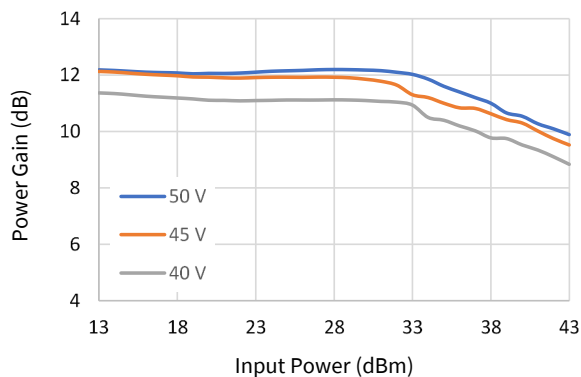
Drain Current vs. Input Power vs. V_{DS}



Gate Current vs. Input Power vs. V_{DS}



Power Gain vs. Input Power vs. V_{DS}

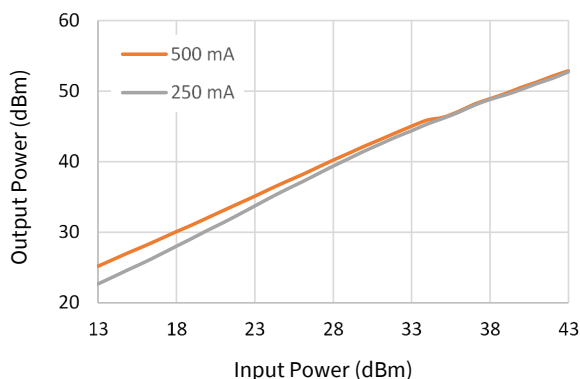


Typical Performance Curves:

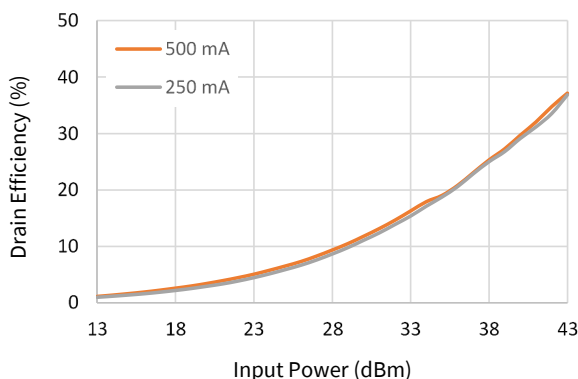
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, CW, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

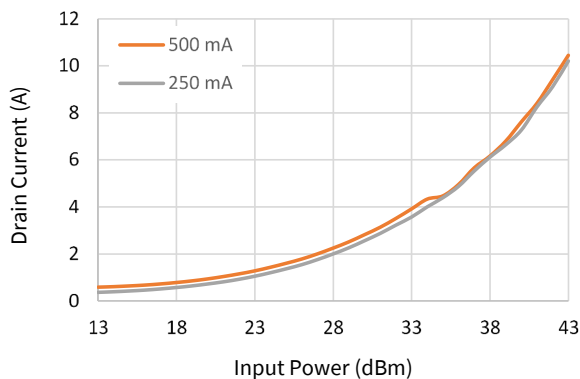
Output Power vs. Input Power vs. I_{DQ}



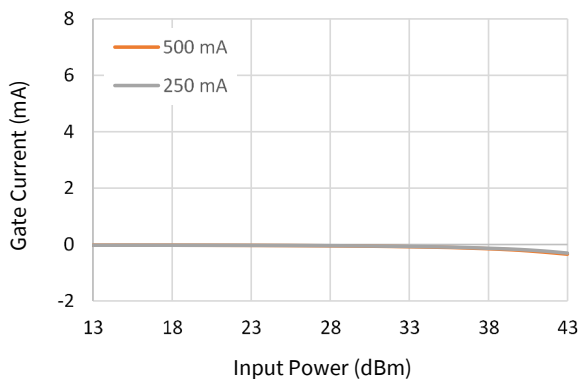
Drain Efficiency vs. Input Power vs. I_{DQ}



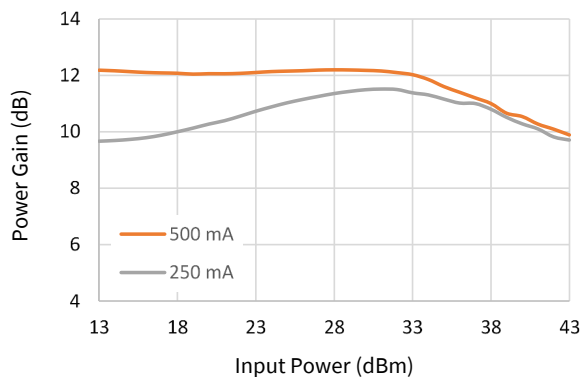
Drain Current vs. Input Power vs. I_{DQ}



Gate Current vs. Input Power vs. I_{DQ}



Power Gain vs. Input Power vs. I_{DQ}

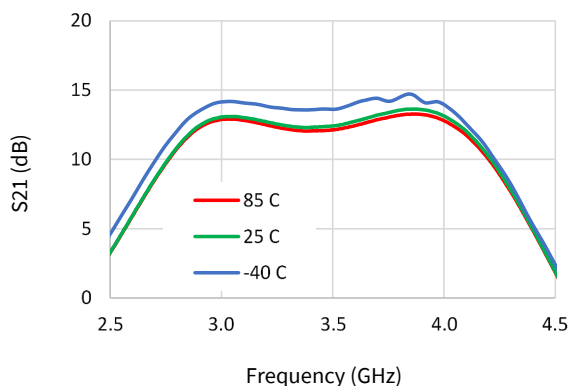


Typical Performance Curves:

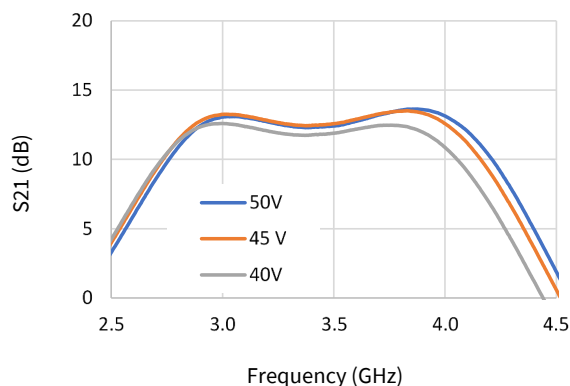
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, $P_{IN} = -20\text{ dBm}$, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

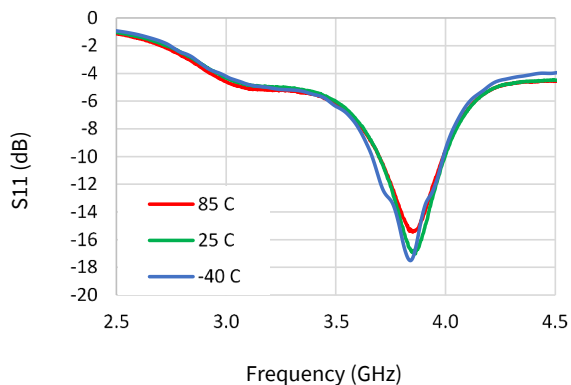
S21 vs. Frequency vs. Temperature



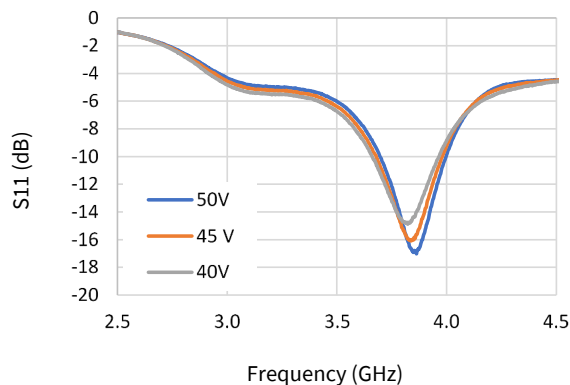
S21 vs. Frequency vs. V_{DS}



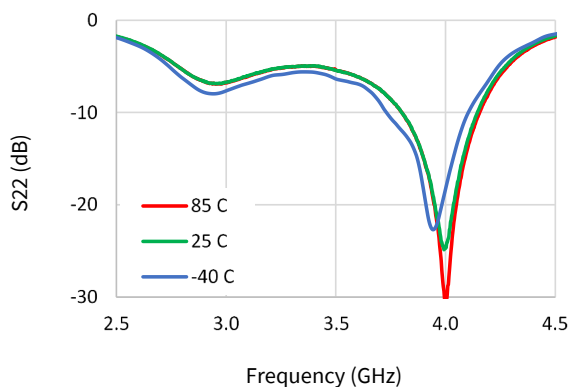
S11 vs. Frequency vs. Temperature



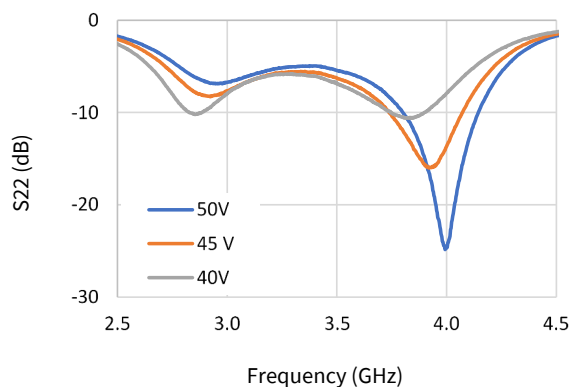
S11 vs. Frequency vs. V_{DS}



S22 vs. Frequency vs. Temperature



S22 vs. Frequency vs. V_{DS}

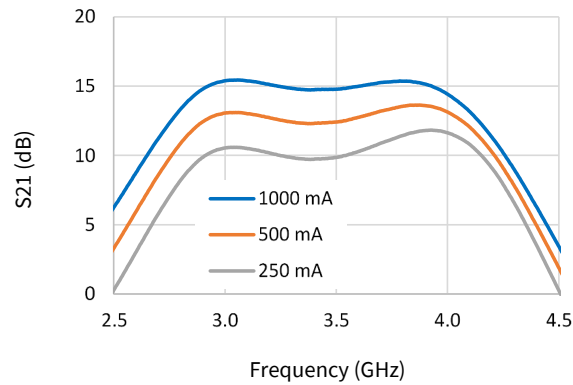


Typical Performance Curves:

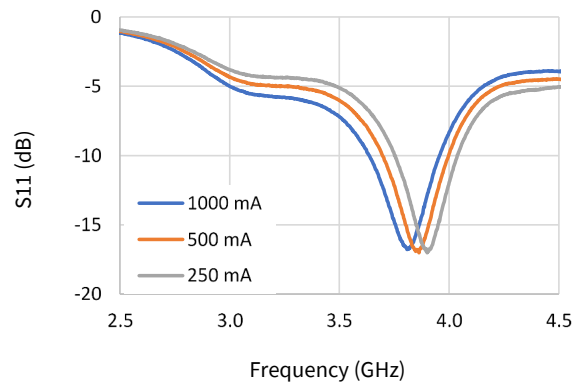
$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, $P_{IN} = -20\text{ dBm}$, $T_B = +25^\circ\text{C}$.

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

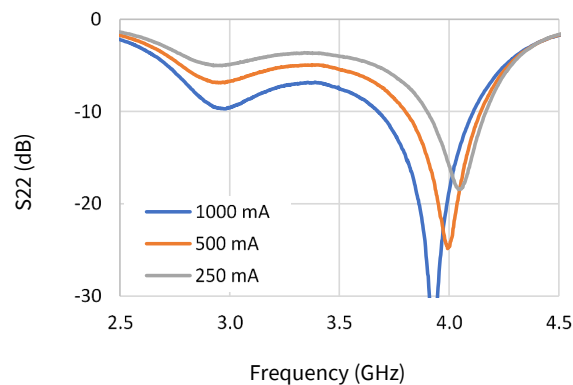
S21 vs. Frequency vs. I_{DQ}



S11 vs. Frequency vs. I_{DQ}



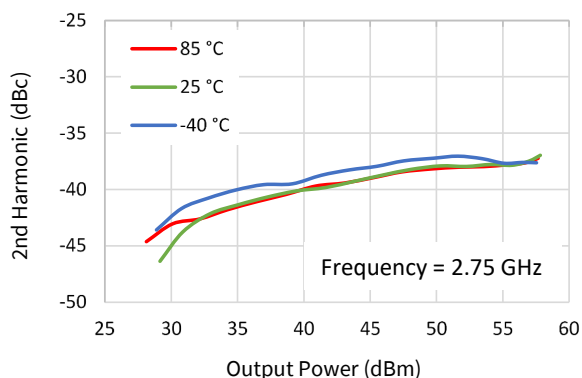
S22 vs. Frequency vs. I_{DQ}



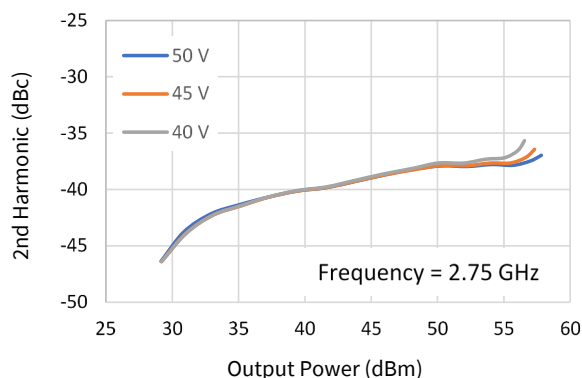
Typical Performance Curves:

$V_D = 50\text{ V}$, $I_{DQ} = 500\text{ mA}$, Pulse Width = 100 μs , Duty Cycle = 10%, $P_{IN} = 46\text{ dBm}$, $T_B = +25^\circ\text{C}$.
For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

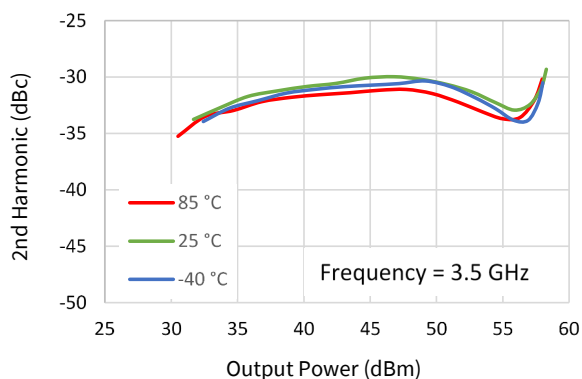
2nd Harmonic vs. Output Power vs. Temperature



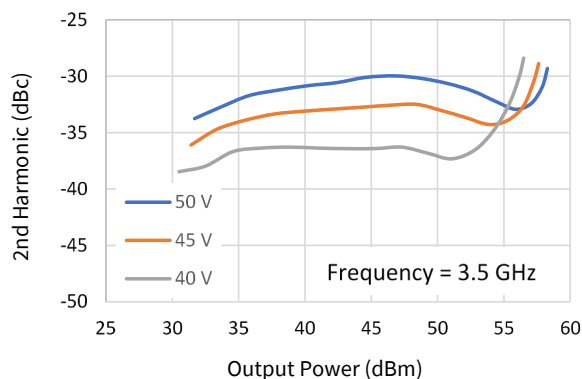
2nd Harmonic vs. Output Power vs. V_{DS}



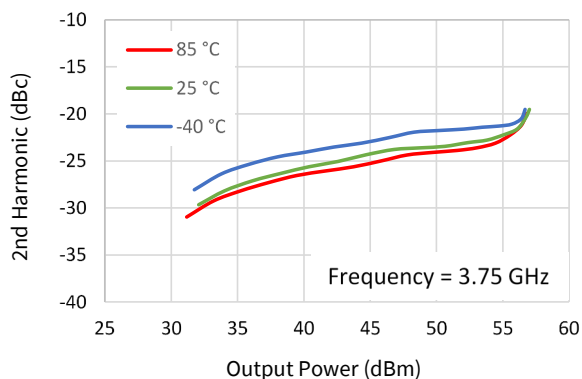
2nd Harmonic vs. Output Power vs. Temperature



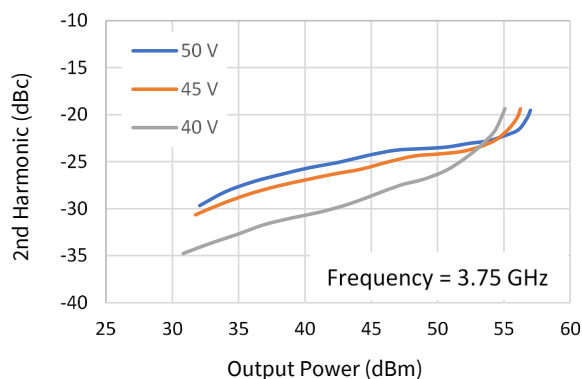
2nd Harmonic vs. Output Power vs. V_{DS}



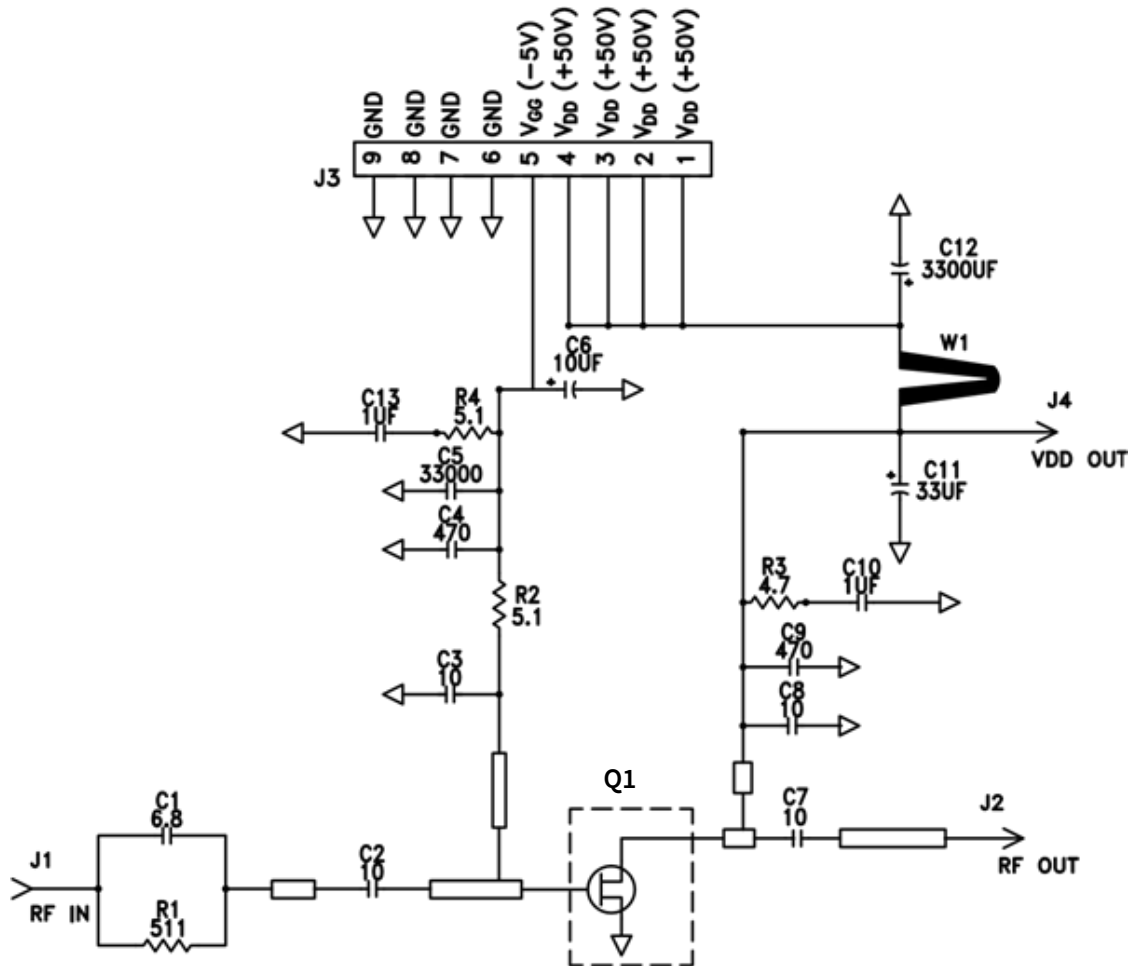
2nd Harmonic vs. Output Power vs. Temperature



2nd Harmonic vs. Output Power vs. V_{DS}



Evaluation Test Fixture 2.75 - 3.75 GHz



Bias Sequencing

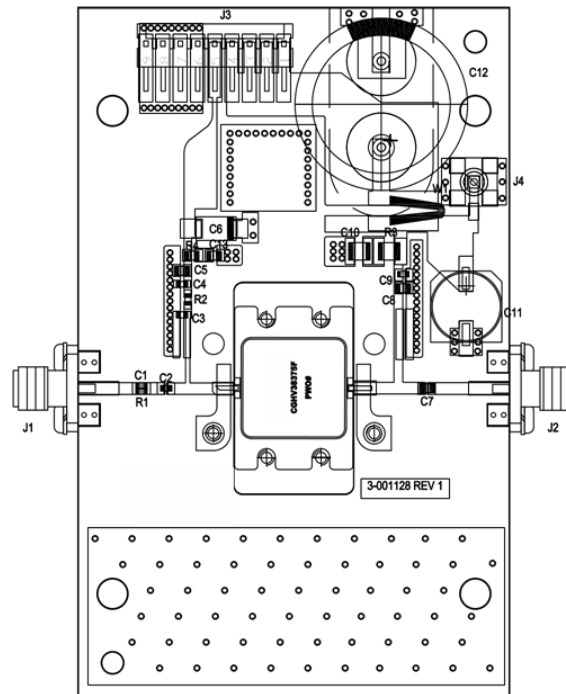
Turning the device ON

1. Set V_{GS} to pinch-off (V_P).
2. Turn on V_{DS} to nominal voltage (50 V).
3. Increase V_{GS} until I_{DS} current is reached.
4. Apply RF power to desired level.

Turning the device OFF

1. Turn the RF power OFF.
2. Decrease V_{GS} down to V_P pinch-off.
3. Decrease V_{DS} down to 0 V.
4. Turn off V_{GS} .

Evaluation Test Fixture 2.75 - 3.75 GHz



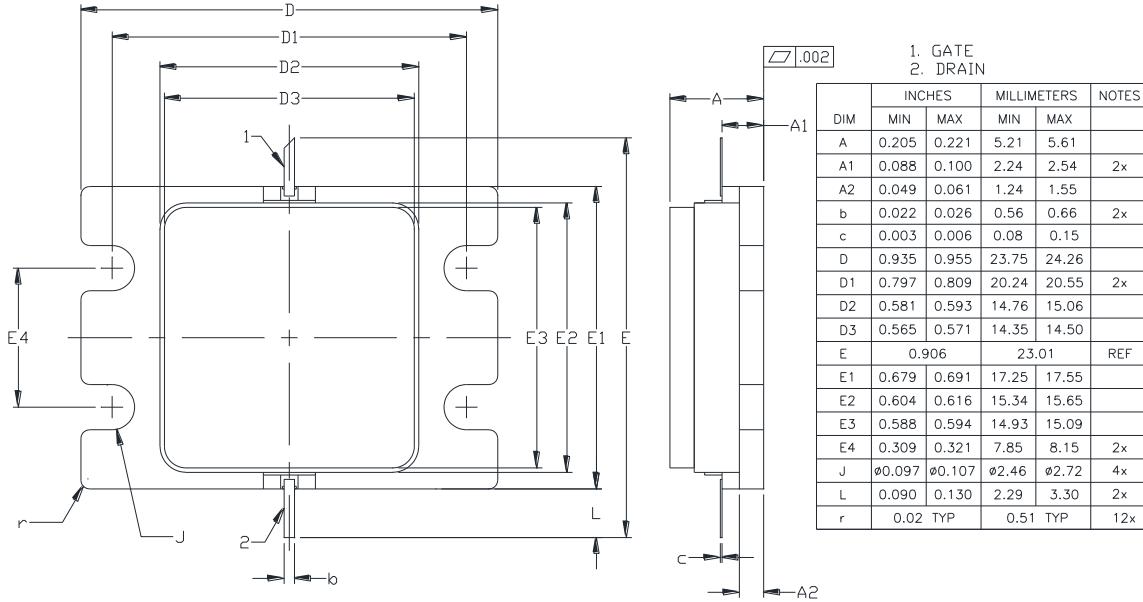
Parts List

Reference Designator	Description	Qty
R1	RES, 511 OHM, +/- 1%, 1/16W,0603	1
R2, R4	RES, 5.1 OHM, +/- 1%, 1/16W,0603	2
R3	RES, 4.7 OHM, 1%, 1/4W, 1206	1
C1	CAP, 6.8 pF, +/- 0.25pF, 250V, 0603	1
C2,C7,C8	CAP, 10 pF, +/- 1%, 250V, 0805	3
C3	CAP, 10 pF, +/-5%,250V, 0603,	1
C4,C9	CAP, 470 pF, 5%, 100V, 0603, X	2
C5	CAP, 33000 pF, 0805, 100V, X7R	1
C6	CAP, 10 µF, 16V, TANTALUM	1
C10	CAP, 1 µF, 100V, 10%, X7R, 1210	1
C11	CAP, 33 µF, 20%, G CASE	1
C12	CAP, 3300 µF, +/-20%, 100V, ELECTROLYTIC	1
C13	CAP, 1 µF, 0805, 100V, X7S	1
J1,J2	CONN, SMA, PANEL MOUNT JACK, FL	2
J3	HEADER RT>PLZ .1CEN LK 9POS	1
J4	CONNECTOR ; SMB, Straight, JACK, SMD	1
W1	CABLE, 18 AWG, 4.2	1
Q1	CGHV38375F	1
PCB	PCB, RF35-TC, 2.5 X 4.0 X 0.030	1

Product Dimensions (Package Type 440226)

NOTES: (UNLESS OTHERWISE SPECIFIED)

1. INTERPRET DRAWING IN ACCORDANCE WITH ANSI Y14.5M-2009
2. ADHESIVE FROM LID MAY EXTEND A MAXIMUM OF .020 BEYOND EDGE OF LID
3. LID MAY BE MISALIGNED TO THE BODY OF PACKAGE BY A MAXIMUM OF .008 IN ANY DIRECTION
4. ALL PLATED SURFACES ARE GOLD OVER NICKEL



MACOM Technology Solutions Inc. ("MACOM"). All rights reserved.

These materials are provided in connection with MACOM's products as a service to its customers and may be used for informational purposes only. Except as provided in its Terms and Conditions of Sale or any separate agreement, MACOM assumes no liability or responsibility whatsoever, including for (i) errors or omissions in these materials; (ii) failure to update these materials; or (iii) conflicts or incompatibilities arising from future changes to specifications and product descriptions, which MACOM may make at any time, without notice. These materials grant no license, express or implied, to any intellectual property rights.

THESE MATERIALS ARE PROVIDED "AS IS" WITH NO WARRANTY OR LIABILITY, EXPRESS OR IMPLIED, RELATING TO SALE AND/OR USE OF MACOM PRODUCTS INCLUDING FITNESS FOR A PARTICULAR PURPOSE, MERCHANTABILITY, INFRINGEMENT OF INTELLECTUAL PROPERTY RIGHT, ACCURACY OR COMPLETENESS, OR SPECIAL, INDIRECT, INCIDENTAL, OR CONSEQUENTIAL DAMAGES WHICH MAY RESULT FROM USE OF THESE MATERIALS.

MACOM products are not intended for use in medical, lifesaving or life sustaining applications. MACOM customers using or selling MACOM products for use in such applications do so at their own risk and agree to fully indemnify MACOM for any damages resulting from such improper use or sale.